

**40V DUAL P-CHANNEL ENHANCEMENT MODE MOSFET**

**Product Summary**

$V_{(BR)DSS}$	$R_{DS(on)}$ max	$I_D$ max (A) $T_A = +25^\circ C$
-40V	25m $\Omega$ @ $V_{GS} = -10V$	-7.6
	45m $\Omega$ @ $V_{GS} = -4.5V$	-6.0

**Description**

This MOSFET has been designed to minimize the on-state resistance and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

**Applications**

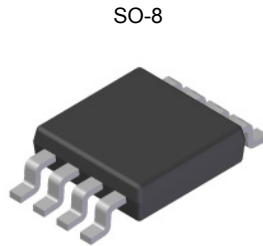
- Motor Control
- Backlighting
- DC-DC Converters
- Printer Equipment

**Features and Benefits**

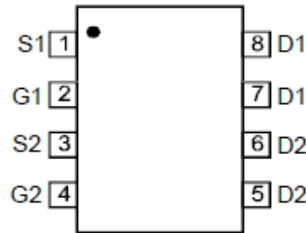
- Low  $R_{DS(on)}$  – Minimizes conduction losses
- Fast switching speed – Minimizes switching losses
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. “Green” Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

**Mechanical Data**

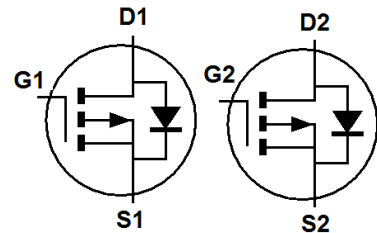
- Case: SO-8
- Case Material: Molded Plastic, “Green” Molding Compound. UL Flammability Classification Rating 94V-0 (Note 1)
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin annealed over Copper lead frame. Solderable per MIL-STD-202, Method 208E3
- Weight: 0.074 grams (approximate)



Top View



Top View Pin-Out



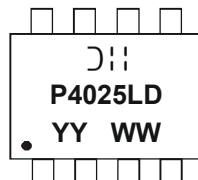
Device symbol

**Ordering Information** (Notes 4 & 5)

Part Number	Compliance	Case	Packaging
DMP4025LSD-13	Standard	SO-8	2500 / Tape & Reel
DMP4025LSDQ-13	Automotive	SO-8	2500 / Tape & Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.
  5. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to [http://www.diodes.com/quality/product\\_grade\\_definitions/](http://www.diodes.com/quality/product_grade_definitions/).

**Marking Information**



- ☐:☐ = Manufacturer's Marking
- P4025LD = Product Type Marking Code
- YYWW = Date Code Marking
- YY = Year (ex: 10 = 2010)
- WW = Week (01 - 53)

**Maximum Ratings** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

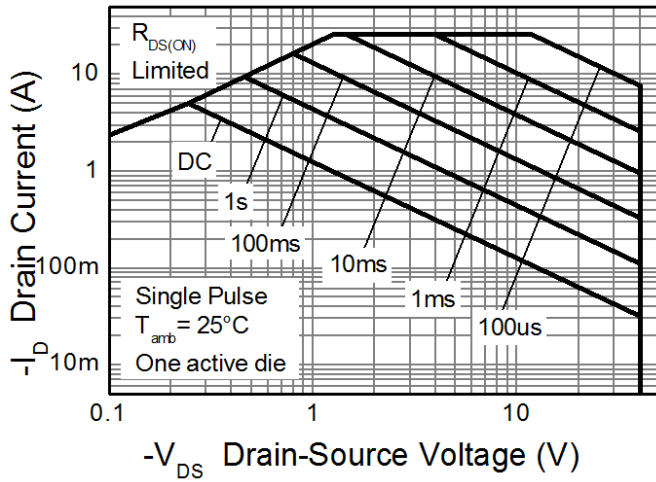
Characteristic			Symbol	Value	Units
Drain-Source Voltage			$V_{DSS}$	-40	V
Gate-Source Voltage			$V_{GSS}$	$\pm 20$	
Continuous Drain Current	$V_{GS} = -10\text{V}$	(Notes 7 & 9)	$I_D$	-7.6	A
		$T_A = +70^\circ\text{C}$ (Notes 7 & 9)		-6.1	
		(Notes 6 & 9)		-5.8	
		(Notes 6 & 10)		-6.9	
Pulsed Drain Current	$V_{GS} = -10\text{V}$	(Notes 8 & 9)	$I_{DM}$	-28.0	
Continuous Source Current (Body diode)			$I_S$	-3.0	
Pulsed Source Current (Body diode)			$I_{SM}$	-28.0	

**Thermal Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

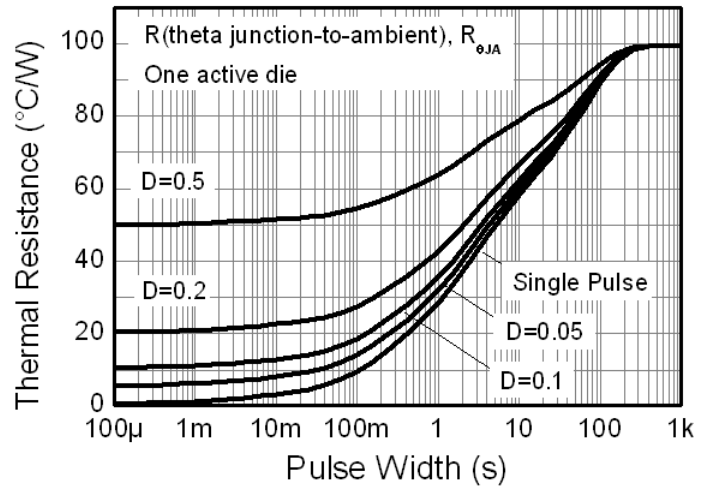
Characteristic		Symbol	Value	Unit
Power Dissipation Linear Derating Factor	(Notes 6 & 9)	$P_D$	1.25 10	W mW/ $^\circ\text{C}$
	(Notes 6 & 10)		1.8 14.3	
	(Notes 7 & 9)		2.14 17.2	
			(Notes 6 & 9)	
(Notes 6 & 10)	70			
(Notes 7 & 9)	58			
Thermal Resistance, Junction to Lead	(Notes 9 & 11)	$R_{\theta JL}$	51	$^\circ\text{C}$
Operating and Storage Temperature Range		$T_J, T_{STG}$	-55 to +150	$^\circ\text{C}$

- Notes:
6. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
  7. Same as note (2), except the device is measured at  $t \leq 10$  sec.
  8. Same as note (2), except the device is pulsed with  $D = 0.02$  and pulse width 300 $\mu\text{s}$ .
  9. For a dual device with one active die.
  10. For a device with two active die running at equal power.
  11. Thermal resistance from junction to solder-point (at the end of the drain lead).

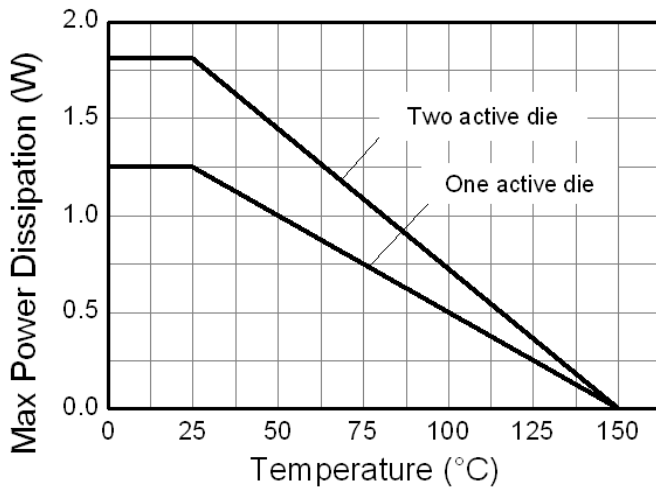
**Thermal Characteristics**



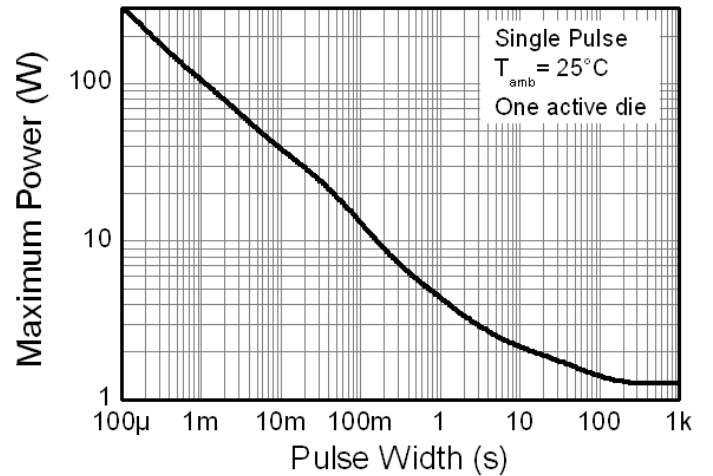
**P-channel Safe Operating Area**



**Transient Thermal Impedance**



**Derating Curve**



**Pulse Power Dissipation**

**Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS</b>						
Drain-Source Breakdown Voltage	$BV_{DS}$	-40	—	—	V	$I_D = -250\mu\text{A}$ , $V_{GS} = 0\text{V}$
Zero Gate Voltage Drain Current	$I_{DSS}$	—	—	-1.0	$\mu\text{A}$	$V_{DS} = -40\text{V}$ , $V_{GS} = 0\text{V}$
Gate-Source Leakage	$I_{GSS}$	—	—	$\pm 100$	nA	$V_{GS} = \pm 20\text{V}$ , $V_{DS} = 0\text{V}$
<b>ON CHARACTERISTICS</b>						
Gate Threshold Voltage	$V_{GS(th)}$	-0.8	-1.3	-1.8	V	$I_D = -250\mu\text{A}$ , $V_{DS} = V_{GS}$
Static Drain-Source On-Resistance (Note 12)	$R_{DS(ON)}$	—	18	25	m $\Omega$	$V_{GS} = -10\text{V}$ , $I_D = -3\text{A}$
			30	45		$V_{GS} = -4.5\text{V}$ , $I_D = -3\text{A}$
Forward Transconductance (Notes 12 & 13)	$g_{fs}$	—	16.6	—	S	$V_{DS} = -5\text{V}$ , $I_D = -3\text{A}$
Diode Forward Voltage (Note 12)	$V_{SD}$	—	-0.7	-1.0	V	$I_S = -1\text{A}$ , $V_{GS} = 0\text{V}$
<b>DYNAMIC CHARACTERISTICS (Note 13)</b>						
Input Capacitance	$C_{iss}$	—	1640	—	pF	$V_{DS} = -20\text{V}$ , $V_{GS} = 0\text{V}$ $f = 1\text{MHz}$
Output Capacitance	$C_{oss}$	—	179	—		
Reverse Transfer Capacitance	$C_{rss}$	—	128	—		
Gate Resistance	$R_g$	—	6.43	—	$\Omega$	$V_{DS} = 0\text{V}$ , $V_{GS} = 0\text{V}$ , $f = 1\text{MHz}$
Total Gate Charge (Note 14)	$Q_g$	—	14.0	—	nC	$V_{GS} = -4.5\text{V}$ $V_{GS} = -10\text{V}$ $V_{DS} = -20\text{V}$ $I_D = -3\text{A}$
Total Gate Charge (Note 14)	$Q_g$	—	33.7	—		
Gate-Source Charge (Note 14)	$Q_{gs}$	—	5.5	—		
Gate-Drain Charge (Note 14)	$Q_{gd}$	—	7.3	—		
Turn-On Delay Time (Note 14)	$t_{D(on)}$	—	6.9	—	ns	$V_{DD} = -20\text{V}$ , $V_{GS} = -10\text{V}$ $I_D = -3\text{A}$
Turn-On Rise Time (Note 14)	$t_r$	—	14.7	—		
Turn-Off Delay Time (Note 14)	$t_{D(off)}$	—	53.7	—		
Turn-Off Fall Time (Note 14)	$t_f$	—	30.9	—		

Notes: 12. Measured under pulsed conditions. Pulse width  $\leq 300\mu\text{s}$ ; duty cycle  $\leq 2\%$   
 13. For design aid only, not subject to production testing.  
 14. Switching characteristics are independent of operating junction temperatures.

**Typical Characteristics**

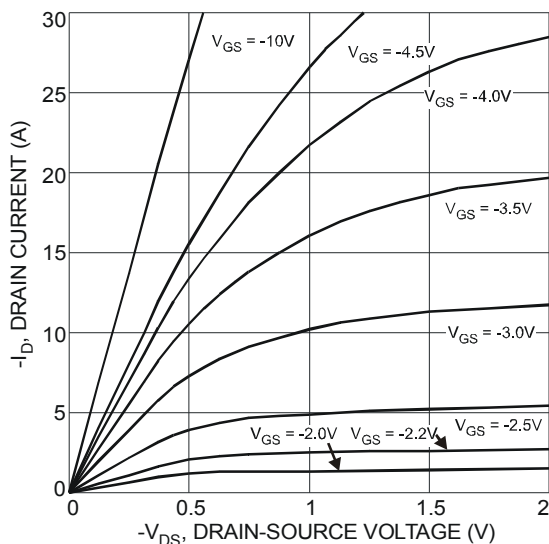


Fig. 1 Typical Output Characteristic

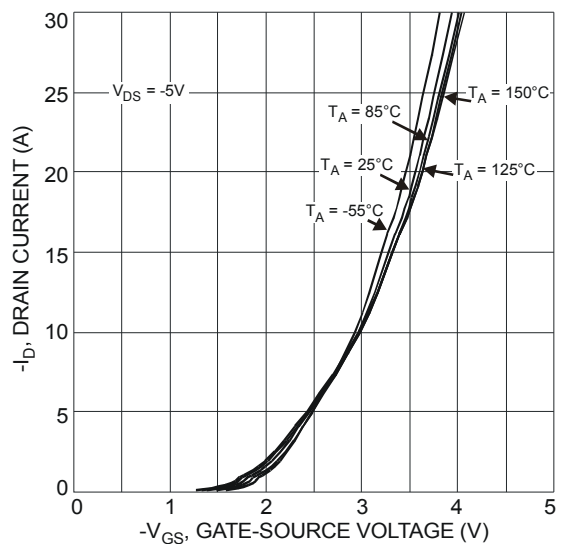


Fig. 2 Typical Transfer Characteristic

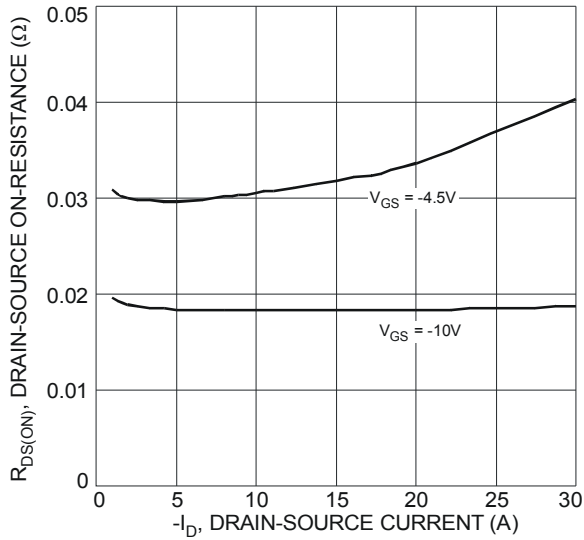


Fig. 3 Typical On-Resistance vs. Drain Current and Gate Voltage

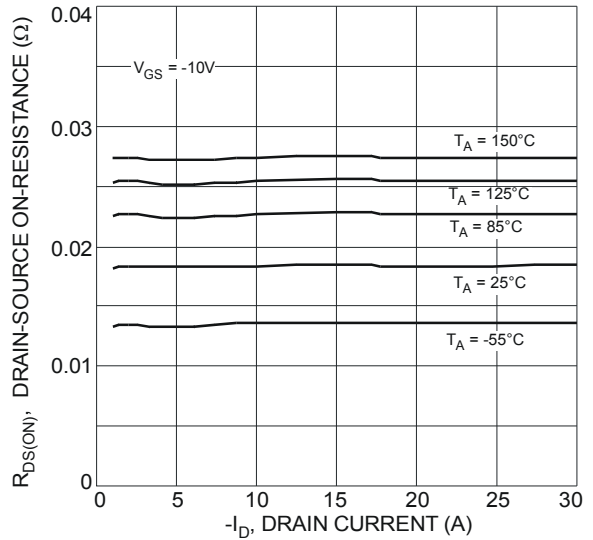


Fig. 4 Typical On-Resistance vs. Drain Current and Temperature

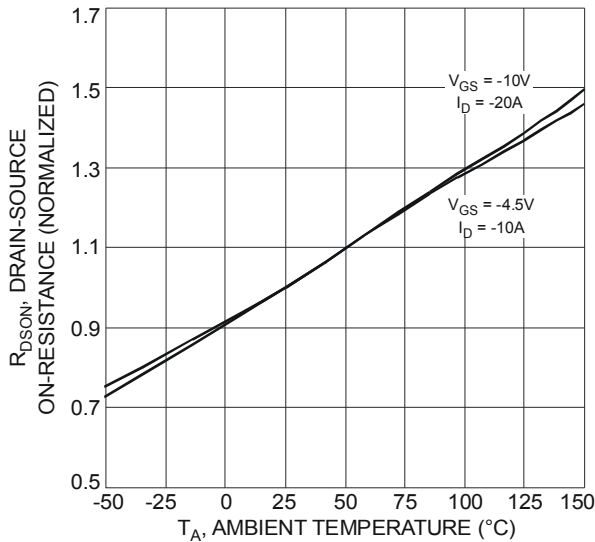


Fig. 5 On-Resistance Variation with Temperature

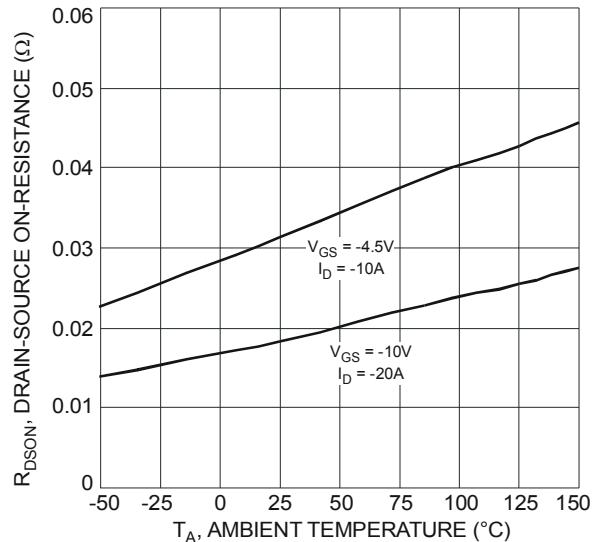


Fig. 6 On-Resistance Variation with Temperature

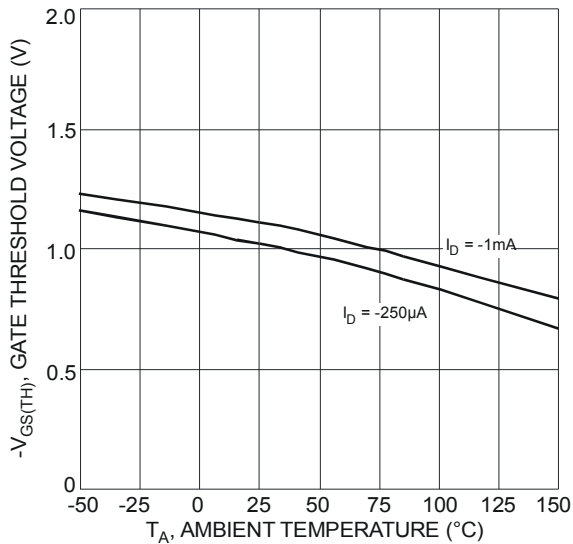


Fig. 7 Gate Threshold Variation vs. Ambient Temperature

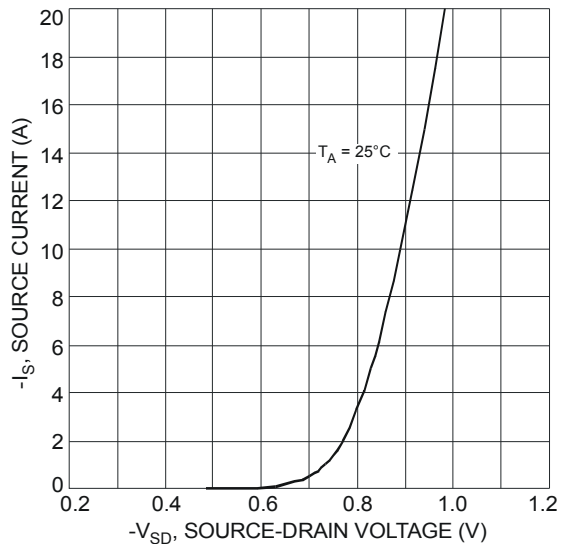


Fig. 8 Diode Forward Voltage vs. Current

**DMP4025LSD**

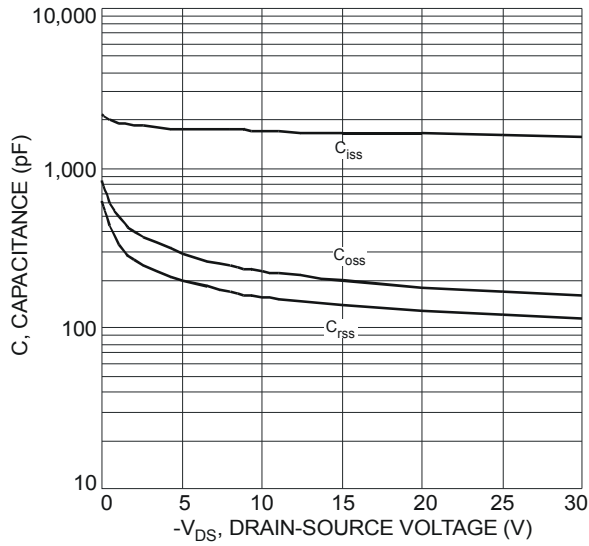


Fig. 9 Typical Total Capacitance

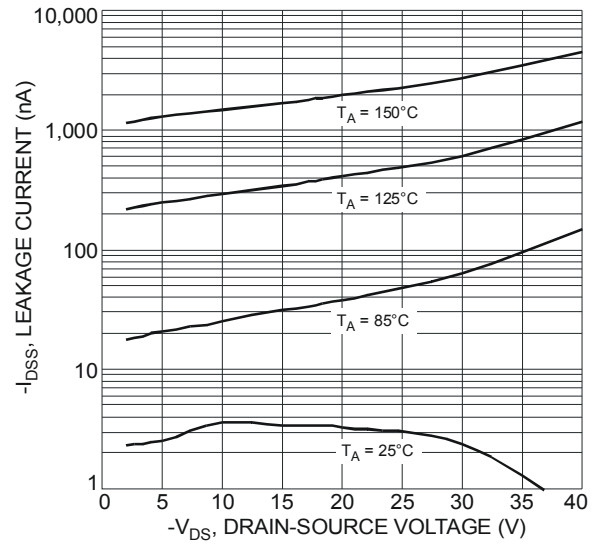


Fig. 10 Typical Leakage Current vs. Drain-Source Voltage

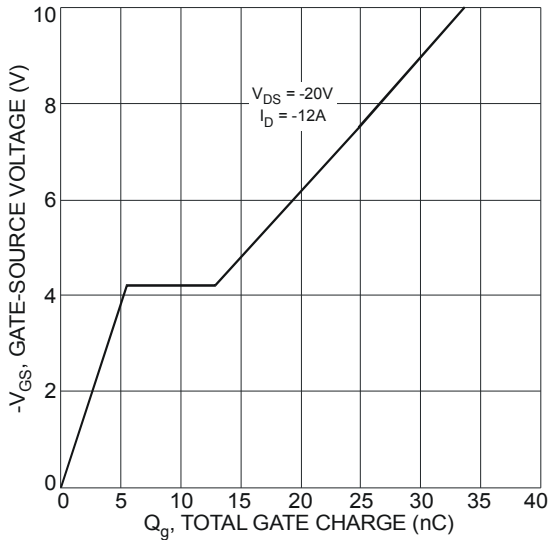
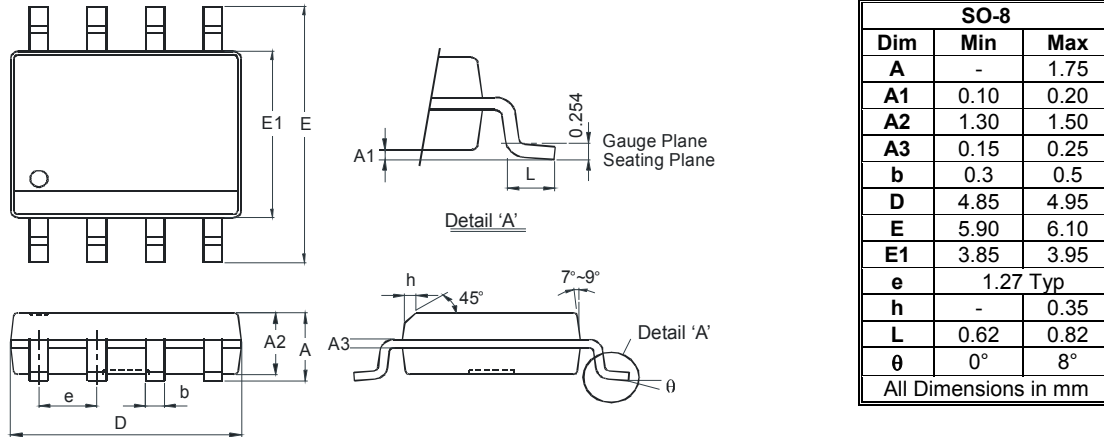


Fig. 11 Gate-Charge Characteristics

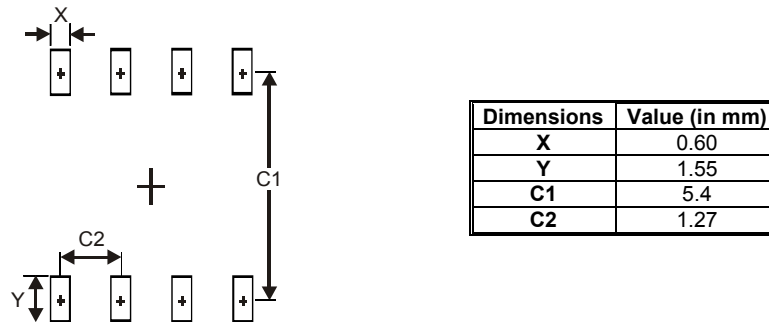
## Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



## Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



**IMPORTANT NOTICE**

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

**LIFE SUPPORT**

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2013, Diodes Incorporated

[www.diodes.com](http://www.diodes.com)



# Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Diodes Incorporated:](#)

[DMP4025LSD-13](#)